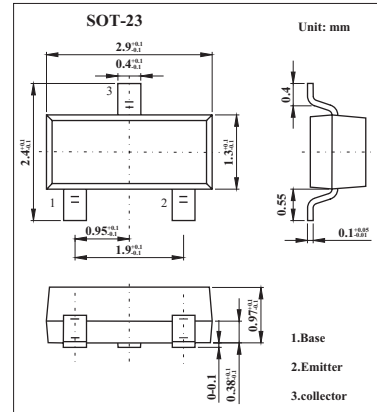


2SD601A

■ Features

- High forward current transfer ratio hFE.
- Low collector to emitter saturation voltage $V_{CE(sat)}$.
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.



■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	60	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	V_{EBO}	7	V
Collector current	I_C	100	mA
Peak collector current	I_{CP}	200	mA
Collector power dissipation	P_C	200	mW
Junction temperature	T_J	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Collector-base voltage	V_{CBO}	$I_C = 20 \mu\text{A}, I_E = 0$	60			V
Collector-emitter voltage	V_{CEO}	$I_C = 2 \text{ mA}, I_B = 0$	50			V
Emitter-base voltage	V_{EBO}	$I_E = 10 \mu\text{A}, I_C = 0$	7			V
Collector-base current	I_{CBO}	$V_{CB} = 20 \text{ V}, I_E = 0 \text{ A}$			0.1	μA
Collector-emitter current	I_{CEO}	$V_{CE} = 10 \text{ V}, I_B = 0 \text{ A}$			100	μA
Forward current transfer ratio	hFE	$V_{CE} = 10 \text{ V}, I_C = 2 \text{ mA}$	160		460	
Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$		0.1	0.3	V
Transition frequency	f_T	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$		150		MHz
Collector output capacitance	C_{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1.0 \text{ MHz}$		3.5		pF
Noise voltage	NV	$V_{CE} = 10 \text{ V}, I_C = 1 \text{ mA}, G_v = 80 \text{ dB}, R_g = 100 \text{ kW}, \text{Function} = \text{FLAT}$		110		mV

■ hFE Classification

Marking	ZQ	ZR	ZS
hFE	160~260	210~340	290~460